Low-power triple buffer Rev. 5 — 24 June 2022

1. General description

The 74AUP3G34 is a triple buffer.

Schmitt trigger action at all inputs makes the circuit tolerant of slower input rise and fall times.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial Power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing a damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78B Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

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3. Ordering information

Table 1. Ordering information

Type number	Package								
	Temperature range	Name	Description	Version					
74AUP3G34DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	<u>SOT765-1</u>					
74AUP3G34GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm	<u>SOT833-1</u>					
74AUP3G34GF	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1 × 0.5 mm	<u>SOT1089</u>					
74AUP3G34GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.0 × 0.35 mm	<u>SOT1116</u>					
74AUP3G34GS	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1.0 × 0.35 mm	<u>SOT1203</u>					
74AUP3G34GX	-40 °C to +125 °C	X2SON8	plastic thermal enhanced extremely thin small outline package; no leads; 8 terminals; body 1.35 × 0.8 × 0.32 mm	<u>SOT1233-2</u>					

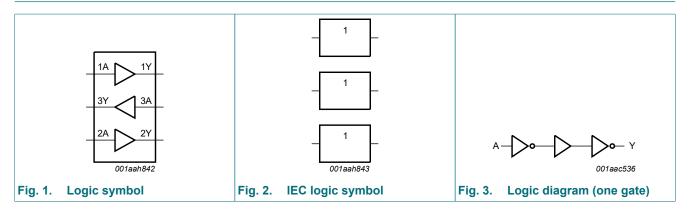
4. Marking

Table 2. Marking codes

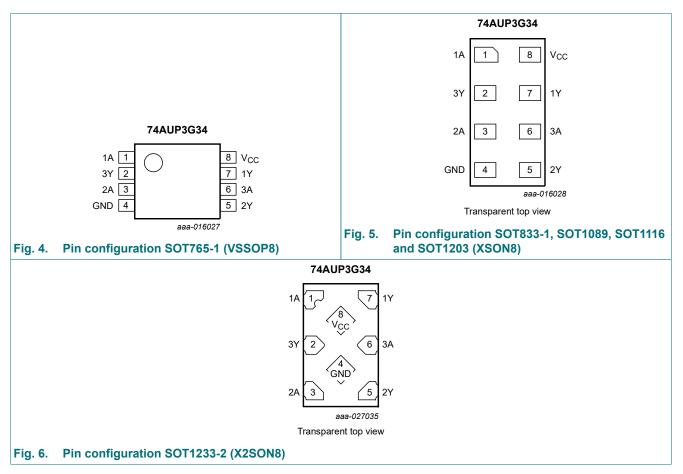
Type number	Marking code[1]
74AUP3G34DC	a34
74AUP3G34GT	a34
74AUP3G34GF	aA
74AUP3G34GN	aA
74AUP3G34GS	aA
74AUP3G34GX	aA

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information



6.1. Pinning

6.2. Pin description

Table 3. Pin description							
Symbol	Pin	Description					
1A, 2A, 3A	1, 3, 6	data input					
1Y, 2Y, 3Y	7, 5, 2	data output					
GND	4	ground (0 V)					
V _{CC}	8	supply voltage					

7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level.

Input	Output
nA	nY
L	L
Н	Н

74AUP3G34

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Мах	Unit
V _{CC}	supply voltage			-0.5	+4.6	V
I _{IK}	input clamping current	V ₁ < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V		-50	-	mA
Vo	output voltage	Active mode and Power-down mode	[1]	-0.5	+4.6	V
lo	output current	$V_{O} = 0 V \text{ to } V_{CC}$		-	±20	mA
I _{CC}	supply current			-	+50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C				
		SOT765-1 (VSSOP8) SOT833-1 (XSON8) SOT1089 (XSON8) SOT1116 (XSON8) SOT1203 (XSON8) SOT1233-2 (X2SON8)	[2] [3] [4] [5] [6] [7]		250 250 250 250 250 300	mW mW mW mW mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT765-1 (VSSOP8) package: Ptot derates linearly with 4.9 mW/K above 99 °C.

[3] For SOT833-1 (XSON8) package: P_{tot} derates linearly with 3.1 mW/K above 68 °C.

[4] For SOT1089 (XSON8) package: P_{tot} derates linearly with 4.0 mW/K above 88 °C.

[5] For SOT1116 (XSON8) package: P_{tot} derates linearly with 4.2 mW/K above 90 °C.

[6] For SOT1203 (XSON8) package: P_{tot} derates linearly with 3.6 mW/K above 81 °C.

[7] For SOT1233-2 (X2SON8) package: Ptot derates linearly with 7.7 mW/K above 118 °C.

9. Recommended operating conditions

Table 6. Operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit					
V _{CC}	supply voltage		0.8	3.6	V					
VI	input voltage		0	3.6	V					
Vo	output voltage	Active mode	0	V _{CC}	V					
		Power-down mode; V_{CC} = 0 V	0	3.6	V					
T _{amb}	ambient temperature		-40	+125	°C					
Δt/ΔV	input transition rise and fall rate	V _{CC} = 0.8 V to 3.6 V	-	200	ns/V					

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
VIH	HIGH-level input	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
	voltage	V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
	voltage	V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$				
	voltage	I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	_	-	V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$				
	voltage	I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
I _I	input leakage current	V_1 = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.2	μA
ΔI _{OFF}	additional power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V;}$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.2	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	40	μA
CI	input capacitance	V_{CC} = 0 V to 3.6 V; V _I = GND or V _{CC}	-	1.0	-	pF
Co	output capacitance	$V_0 = GND; V_{CC} = 0 V$	-	1.8	-	pF

Low-power triple buffer

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = -4	0 °C to +85 °C	1		1		
VIH	HIGH-level input	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
	voltage	V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
	voltage	V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$				
	voltage	I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V		-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$				
	voltage	I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
l _l	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μA
ΔI _{OFF}	additional power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V};$ - $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$ -		-	±0.6	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.9	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	50	μA

Low-power triple buffer

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	0 °C to +125 °C	1		I		
VIH	HIGH-level input	V _{CC} = 0.8 V	0.75 × V _{CC}	-	-	V
	voltage	V _{CC} = 0.9 V to 1.95 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input	V _{CC} = 0.8 V	-	-	0.25 × V _{CC}	V
	voltage	V _{CC} = 0.9 V to 1.95 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$				
	voltage	I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$				
	voltage	I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		$I_{\rm O}$ = 2.3 mA; $V_{\rm CC}$ = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
l _l	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.75	μA
ΔI _{OFF}	additional power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.75	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	75	μA

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit, see Fig. 8.

Symbol	Parameter	Conditions	T,	amb = 25	°C	T _{an} -40 °C te	_{nb} = o +85 °C	T _{ar} -40 °C to	_{nb} = > +125 °C	Unit
			Min	Typ[1]	Мах	Min	Max	Min	Max	1
C _L = 5 p	F									
t _{pd}	propagation	nA to nY; see <u>Fig. 7</u> [2]								
	delay	V _{CC} = 0.8 V	-	14.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.6	4.7	9.2	2.0	10.0	2.0	11.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.1	3.4	5.7	1.6	6.5	1.6	7.2	ns
		V _{CC} = 1.65 V to 1.95 V	1.8	2.9	4.5	1.4	5.2	1.4	5.8	ns
		V _{CC} = 2.3 V to 2.7 V	1.5	2.3	3.5	1.2	4.2	1.2	4.6	ns
		V _{CC} = 3.0 V to 3.6 V	1.4	2.1	3.2	1.0	3.8	1.0	4.2	ns
C _L = 10	pF			1		1				
t _{pd}	propagation	nA to nY; see Fig. 7 [2]								
	delay	V _{CC} = 0.8 V	-	18.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.2	5.6	10.9	2.3	11.8	2.3	13.1	ns
		V _{CC} = 1.4 V to 1.6 V	2.6	4.1	6.7	1.9	7.7	1.9	8.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.3	3.4	5.3	1.7	6.2	1.7	6.9	ns
		V _{CC} = 2.3 V to 2.7 V	2.0	2.9	4.2	1.5	5.0	1.5	5.5	ns
		V _{CC} = 3.0 V to 3.6 V	1.7	2.6	3.8	1.4	4.6	1.4	5.1	ns
C _L = 15	pF		1	1	1				1	1
t _{pd}	propagation	nA to nY; see Fig. 7 [2]								
	delay	V _{CC} = 0.8 V	-	21.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.6	6.4	12.6	2.6	13.8	2.6	15.2	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	4.6	7.6	2.2	8.9	2.2	9.8	ns
		V _{CC} = 1.65 V to 1.95 V	2.6	3.9	6.0	2.0	7.2	2.0	7.9	ns
		V _{CC} = 2.3 V to 2.7 V	2.3	3.3	4.8	1.8	5.7	1.8	6.3	ns
		V _{CC} = 3.0 V to 3.6 V	2.1	3.1	4.2	1.6	5.0	1.6	5.5	ns
C _L = 30	pF	1		1		•			-	
t _{pd}		nA to nY; see Fig. 7 [2]								
	delay	V _{CC} = 0.8 V	-	32.1	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.8	8.7	16.3	3.6	18.9	3.6	20.8	ns
		V _{CC} = 1.4 V to 1.6 V	4.0	6.2	10.3	3.4	12.2	3.4	13.4	ns
		V _{CC} = 1.65 V to 1.95 V	3.6	5.2	8.1	3.2	9.8	3.2	10.8	ns
		V _{CC} = 2.3 V to 2.7 V	3.0	4.4	6.4	2.7	7.7	2.7	8.5	ns
		V _{CC} = 3.0 V to 3.6 V	2.9	4.2	5.6	2.5	6.5	2.5	7.2	ns

Low-power triple buffer

Symbol	Parameter	arameter Conditions				T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit	
			Min	Typ[1]	Max	Min	Max	Min	Max		
C _L = 5 p	F, 10 pF, 15 p	F and 30 pF									
10 1	dissipation	$ f_i = 1 \text{ MHz}; \qquad [3] [4] $									
	capacitance	V _{CC} = 0.8 V	-	2.5	-	-	-	-	-	pF	
		V _{CC} = 1.1 V to 1.3 V	-	2.6	-	-	-	-	-	pF	
		V _{CC} = 1.4 V to 1.6 V	-	2.7	-	-	-	-	-	pF	
		V _{CC} = 1.65 V to 1.95 V	-	2.9	-	-	-	-	-	pF	
		V _{CC} = 2.3 V to 2.7 V	-	3.4	-	-	-	-	-	pF	
		V _{CC} = 3.0 V to 3.6 V	-	4.0	-	-	-	-	-	pF	

All typical values are measured at nominal V_{CC}. [1]

[2]

 t_{pd} is the same as t_{PLH} and t_{PHL} . All specified values are the average typical values over all stated loads. [3]

[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

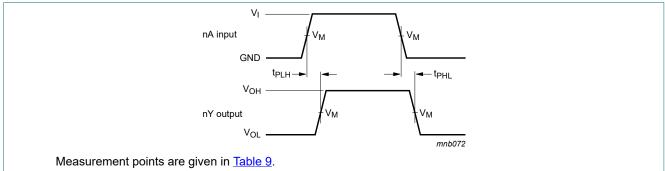
 f_o = output frequency in MHz;

C_L = load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

11.1. Waveform and test circuit



Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

The data input (nA) to output (nY) propagation delays Fig. 7.

Table 9. Measurement points

Supply voltage	Input	Output				
V _{cc}	V _M	V_{M} V_{I} $t_{r} = t_{f}$ V_{I}				
0.8 V to 3.6 V	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns	$0.5 \times V_{CC}$		

Low-power triple buffer

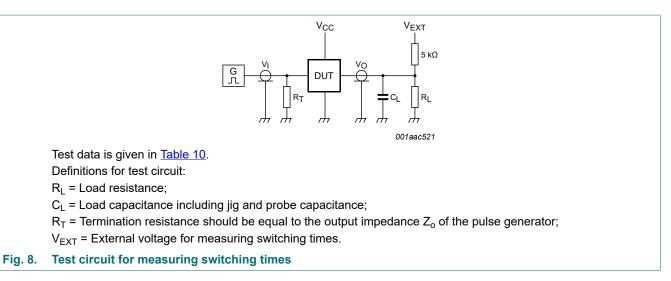


Table 10. Test data

Supply voltage	Load		V _{EXT}		
V _{cc}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF, and 30 pF	$5 \text{ k}\Omega$ or $1 \text{ M}\Omega$	open	GND	2 × V _{CC}

[1] For measuring enable and disable times $R_L = 5 k\Omega$.

For measuring propagation delays, setup and hold times and pulse width R_L = 1 M Ω .

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Low-power triple buffer

12. Package outline

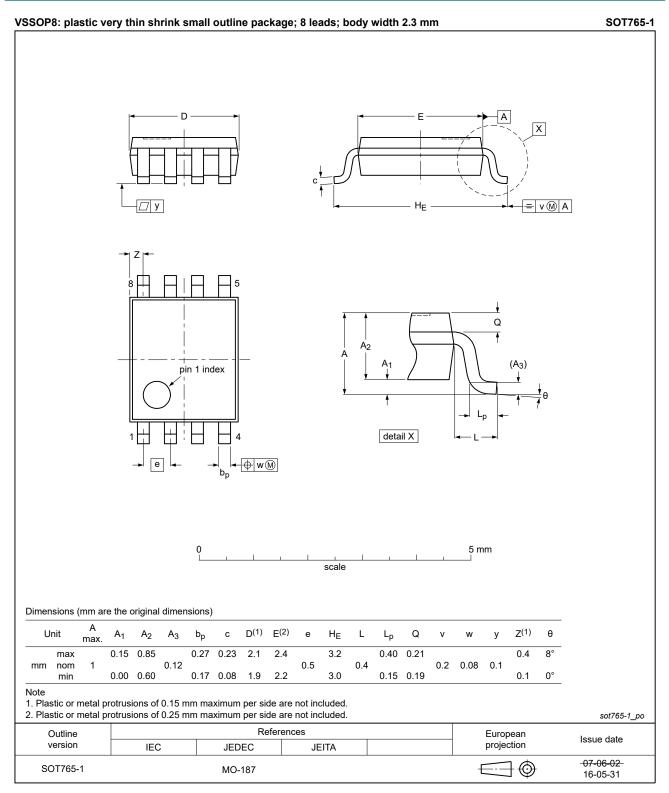


Fig. 9. Package outline SOT765-1 (VSSOP8)

Low-power triple buffer

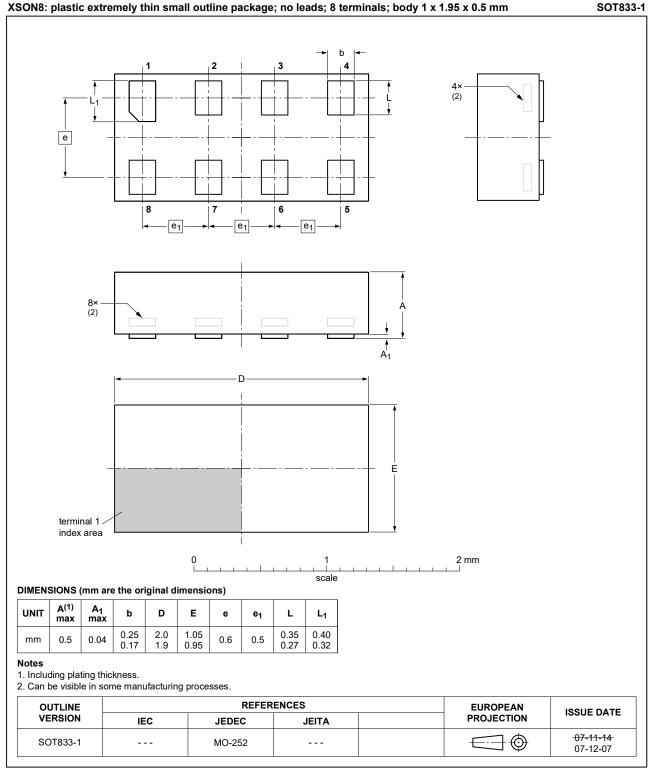
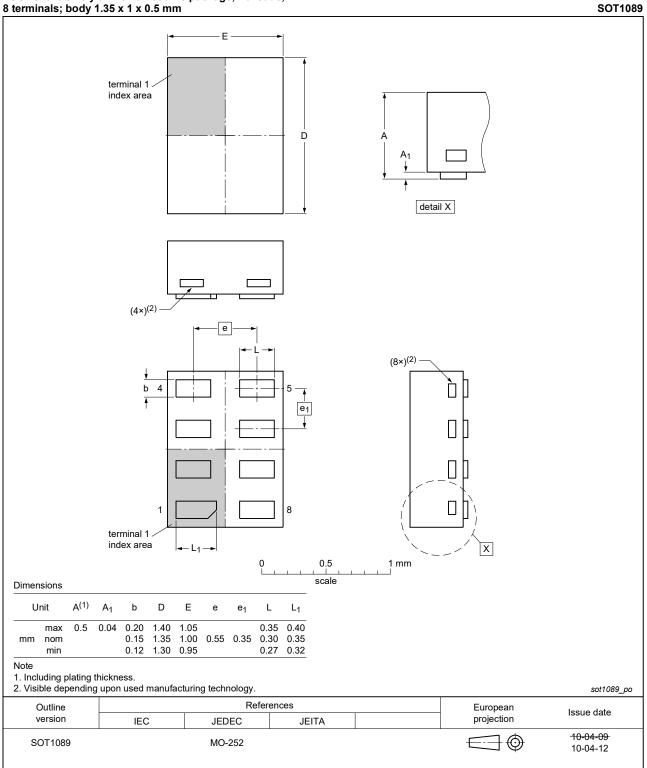


Fig. 10. Package outline SOT833-1 (XSON8)

Low-power triple buffer

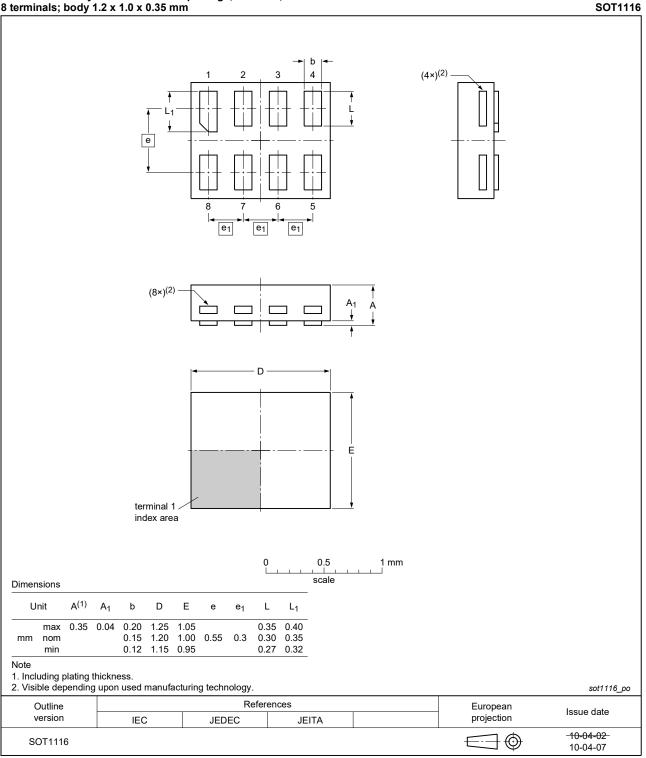


XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1 x 0.5 mm

Fig. 11. Package outline SOT1089 (XSON8)

Low-power triple buffer

XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.2 x 1.0 x 0.35 mm





XSON8: extremely thin small outline package; no leads;

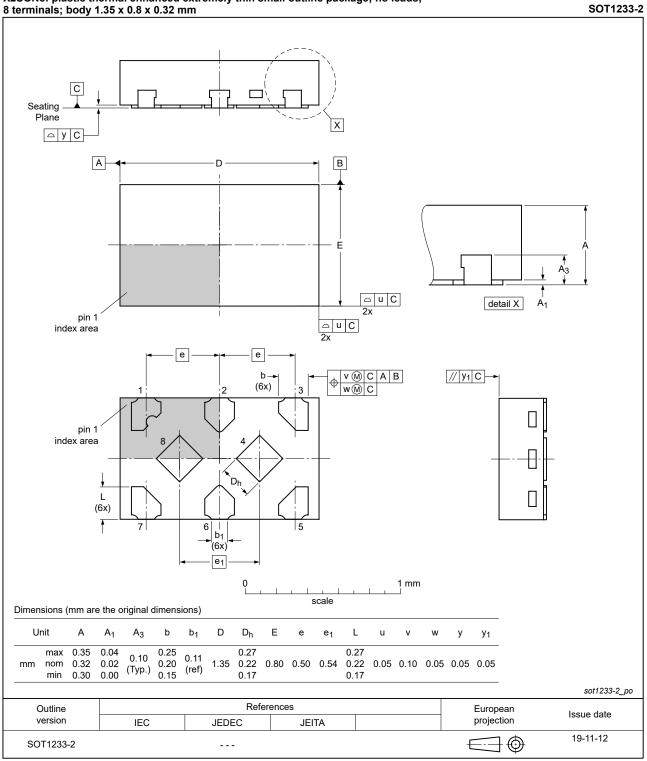
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8 terminals; body 1.35 x 1.0 x 0.35 mm SOT1203 b (4×)⁽²⁾ 4 3 2 е 8 6 5 e₁e₁ e₁ $(8 \times)^{(2)}$ А С ٦ D E terminal 1 index area 0.5 1 mm 0 1 1 1 scale Dimensions Unit A⁽¹⁾ A₁ b D Е L е e₁ L_1 0.35 0.04 0.20 1.40 1.05 0.35 0.40 max 0.15 1.00 0.55 0.35 0.30 0.35mm nom 1.35 min 0.12 1.30 0.95 0.27 0.32 Note 1. Including plating thickness. 2. Visible depending upon used manufacturing technology. sot1203_po References Outline European Issue date version projection IEC JEDEC JEITA 10-04-02 SOT1203 \blacksquare 10-04-06



Low-power triple buffer



X2SON8: plastic thermal enhanced extremely thin small outline package; no leads; 8 terminals; body 1.35 x 0.8 x 0.32 mm

Fig. 14. Package outline SOT1233-2 (X2SON8)

Product data sheet

13. Abbreviations

Acronym	Description	
CDM	Charged Device Model	
DUT	Device Under Test	
ESD	ElectroStatic Discharge	
НВМ	Human Body Model	
MM	Machine Model	

14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74AUP3G34 v.5	20220624	Product data sheet	-	74AUP3G34 v.4	
Modifications:		X2SON8) package change _{ot} total power dissipation of	•	,	
74AUP3G34 v.4	20190725	Product data sheet	-	74AUP3G34 v.3	
Modifications:	• <u>Table 5</u> : De	Table 0. Defaulty values for 1 tot total power dissipation updated.			
74AUP3G34 v.3	20170703	Product data sheet	-	74AUP3G34 v.2	
Modifications:	guidelines • Legal texts • Type numb	of this data sheet has been of Nexperia. have been adapted to the er 74AUP3G34GX (SOT12 er 74AUP3G34GD remove	new company nar 233 / X2SON8) ad	ne where appropriate.	
74AUP3G34 v.2	20161011	Product data sheet	-	74AUP3G34 v.1	
Modifications:	Type numb	ers 74AUP3G34DP remov	ed.		
74AUP3G34 v.1	20141218	Product data sheet	-	-	

Low-power triple buffer

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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Product data sheet

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